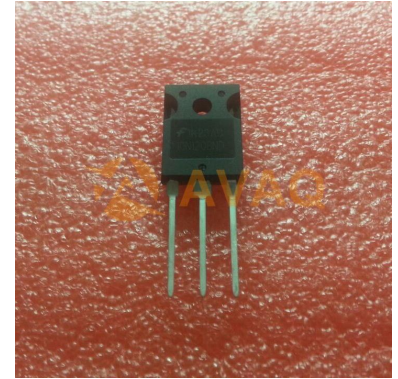


Trans IGBT Chip N-CH 1200V 35A 298mW 3-Pin(3+Tab) TO-247 Tube



Images are for reference only

[Inquiry](#)

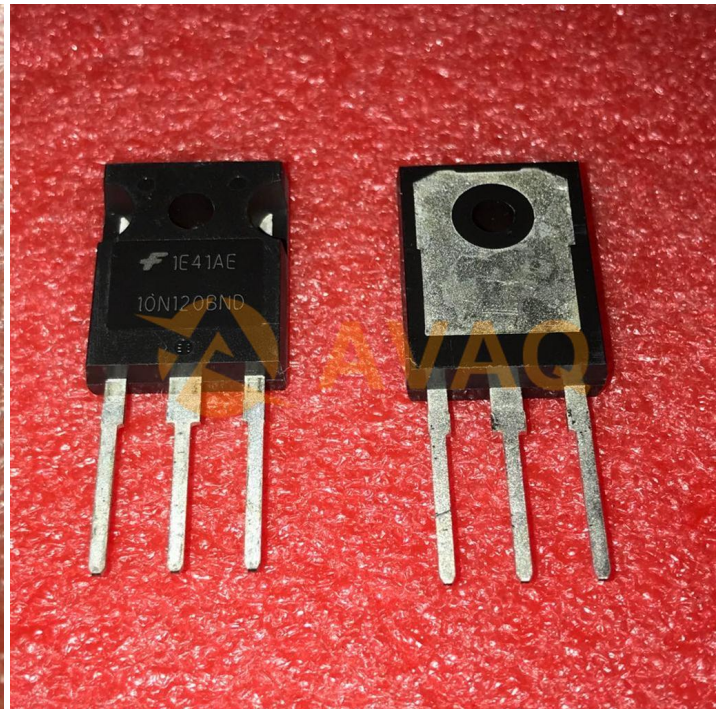
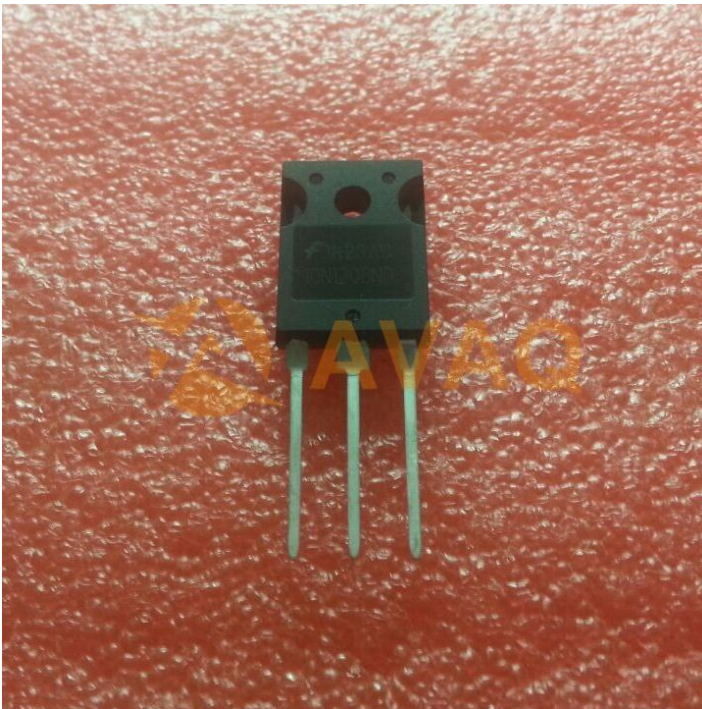
Manufacturer:	ON Semiconductor, LLC
Package/Case:	TO-247
Product Type:	Thyristors
Lifecycle:	LTB

General Description

HGTG10N120BND is based on Non- Punch Through(NPT) IGBT designs. The IGBT is ideal for many high voltage switching applications operating at moderate frequencies where low conduction losses are essential, such as UPS, solar inverter, motor control and power supplies.

Application

Uninterruptible Power Supply



Recommended For You

HGTG20N60B3D

ON Semiconductor, LLC

TO-247

HGTG11N120CND

ON Semiconductor, LLC

TO-247

HGTG20N60B3

ON Semiconductor, LLC

TO-247

HGTP3N60A4

ON Semiconductor, LLC

TO-220

HGTG11N120CN

ON Semiconductor, LLC

TO-247

HGTG12N60A4D

ON Semiconductor, LLC

TO-247

HGTP7N60C3D

ON Semiconductor, LLC

TO-220

HGTP10N120BN

ON Semiconductor, LLC

TO-220

HGTG27N120BN

ON Semiconductor, LLC

TO-247

HGTG30N60C3D

ON Semiconductor, LLC

TO-247

HGTG30N60B3

ON Semiconductor, LLC

TO-247

HGTG30N60A4D

ON Semiconductor, LLC

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HGTP7N60B3D

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HGTG40N60B3

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HGTG40N60A4

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